

N-Channel 150 V (D-S) Super Junction Power MOSFET

PRODUCT SUMMARY							
V _{DS} (V)	R _{DS(on)} (mΩ)(Typ.)	I _D (A)	Q _g (Typ.)				
150	15 at V _{GS} = 10 V	50	43 nC				

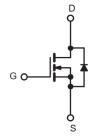
FEATURES

- DT-SJ Power MOSFET
- Low R_{DS(ON)}×FOM
- Extremely low switching loss
- · Fast switching and soft recovery

RoHS

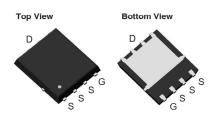
APPLICATIONS

- Motor driver
- Switching voltage regulator
- DC-DC convertor



N-Channel MOSFET

DFN5X6 Pin Configuration



ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage	V _{DS}	150	V			
Gate-Source Voltage	V _{GS}	± 20	7 v			
Continuous Drain Current /T 150 °C)3	T _C = 25 °C	1	50			
Continuous Drain Current (T _J = 150 °C) ^a	T _C = 100 °C	☐ I _D	32	A		
Pulsed Drain Current ^b	I _{DM}	200				
Single Avalanche Energy	E _{AS}	29	mJ			
Maximum Dayyar Dissipations	T _C = 25 °C	В	110	10/		
Maximum Power Dissipation ^c	T _C = 100 °C	P_{D}	44	W		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +150	°C		

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient (PCB Mount) ^d	R _{thJA}	62	°C/W		
Junction-to-Case (Drain)	R _{thJC}	1.14			

Notes

- $a. \ \ \, \text{Calculated continuous current based on maximum allowable junction temperature}.$
- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of R_{0JA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper,in a still air environment with Ta=25 °C.



PARAMETER	SYMBOL	IBOL TEST CONDITIONS		TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	150	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.5	-	4.5	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 135 V, V _{GS} = 0 V	-	-	1	μA
Drain-Source On-State Resistance a R		V _{GS} = 10 V, I _D = 20 A	-	15	18	mΩ
Dynamic ^b						
Input Capacitance	C _{iss}		-	3340	-	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 100 \text{ kHz}$	-	1100	-	pF
Reverse Transfer Capacitance	C _{rss}		-	105	-	
Total Gate Charge ^c	Qg		-	43	-	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	-	17	-	nC
Gate-Drain Charge ^c	Q _{gd}		-	10	-	
Gate Resistance	R_g	f = 1 MHz	-	2.8	-	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	18	-	
Rise Time ^c	t _r	$V_{DS} = 80 \text{ V}, I_D = 20 \text{ A},$	-	12	-	
Turn-Off Delay Time ^c	t _{d(off)}	$V_{GS}=10~V,~R_{g}=2\Omega$	-	30	-	ns
Fall Time ^c	t _f		-	10	-	
Drain-Source Body Diode Ratings ar	nd Characteris	stics ^b (T _C = 25 °C)				
Continuous Source Current	Is	T _C = 25 °C	-	-	50	Α
Pulsed Current	I _{SM}		-	-	200	Α
Forward Voltage ^a	V _{SD}	I _S = 20 A, V _{GS} = 0 V	-	-	1.3	V
Reverse Recovery Time t _{rr}			-	101	-	ns
Reverse Recovery Charge	Recovery Charge Q_{rr} Is = 10 A, di/dt = 100 A/µs		-	254	-	nC
Peak reverse recovery current	I _{rrm}		-	4.4	-	Α

Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

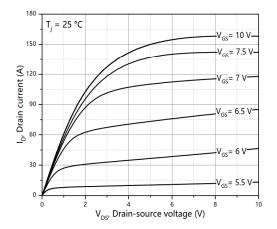


Figure 1. Typ. output characteristics

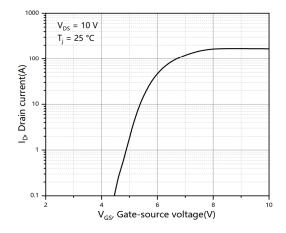


Figure 2. Typ. transfer characteristics

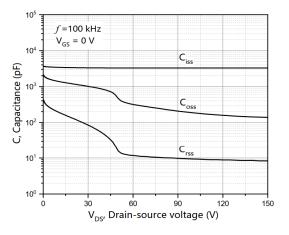


Figure 3. Typ. capacitances

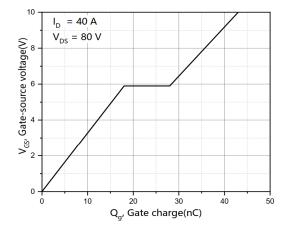


Figure 4. Typ. gate charge

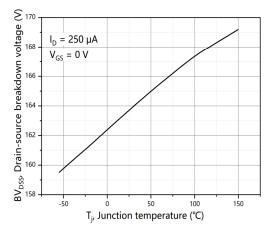


Figure 5. Drain-source breakdown voltage

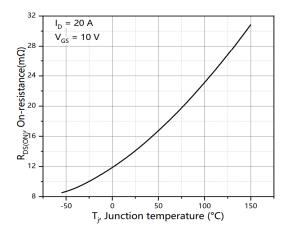


Figure 6. Drain-source on-state resistance



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

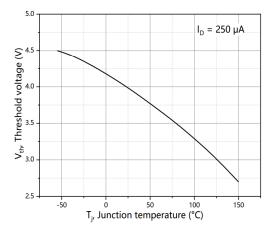
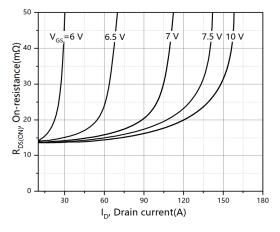


Figure 7. Threshold voltage

Figure 8. Forward characteristic of body diode



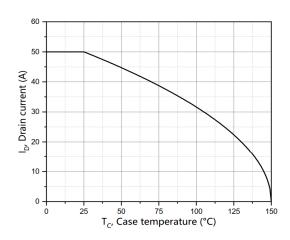
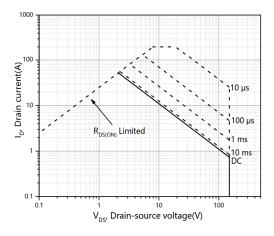


Figure 9. Drain-source on-state resistance

Figure 10. Drain current



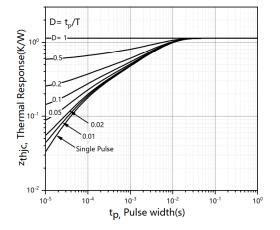
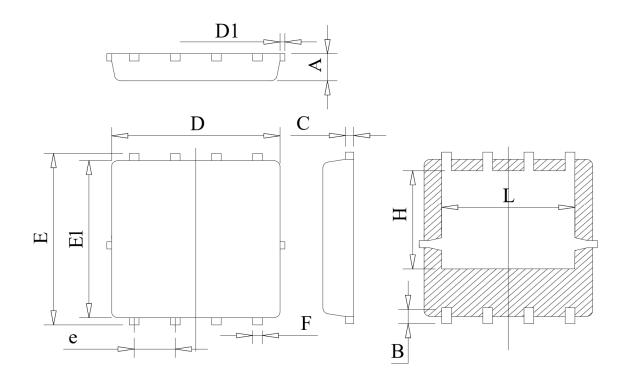


Figure 11. Safe operation area T_C=25℃

Figure 12. Max. transient thermal impedance



DFN5*6-8L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Unit: mm

Symbol	Min	Тур	Max
A	0.78	0.95	1.12
В	0.45	0.58	0.78
С	0.18	0.254	0.36
D	4.70	5.20	5.45
D1			0.18
Е	5.85	6.05	6.25
E1	5.38	5.55	5.98
e	1.15	1.27	1.40
F	0.18	0.30	0.52
Н	3.25	3.47	3.70
L	3.75	4.00	4.25





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